NSN 5961-01-026-9396

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-026-9396 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 8.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 1.00 amperes repetitive peak forward current blank and 500.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector **Transfer Ratio:** 20.0 static forward current transfer ratio, common-emitter and 60.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release5061 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No

NSN 5961-01-026-9396 Transistor - Page 2 of 2



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